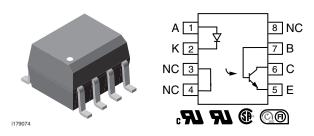


Vishay Semiconductors

Optocoupler, Phototransistor Output, With Base Connection in SOIC-8 Package, 110 °C Rated



LINKS TO ADDITIONAL RESOURCES



DESCRIPTION

The 110 °C 1206AT, 1207AT, 1208AT are optically coupled pairs with a gallium arsenide infrared LED and a silicon NPN phototransistor. Signal information, including a DC level, can be transmitted by the device while maintaining a high degree of electrical isolation between input and output. This family comes in a standard SOIC-8 small outline package for surface mounting which makes them ideally suited for high density application with limited space. In addition to eliminating through-hole requirements, this package conforms to standards for surface mounted devices.

A specified minimum and maximum CTR allows a narrow tolerance in the electrical design of the adjacent circuits. The high BV_{CEO} of 70 V gives a higher safety margin compared to the industry standard 30 V.

FEATURES

- Operating temperature from -55 °C to +110 °C
- High BV_{CFO}, 70 V
- Isolation test voltage, 4000 V_{RMS}
- Industry standard SOIC-8 surface mountable package



- Compatible with dual wave, vapor phase and IR reflow soldering
- Lead (Pb)-free component
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- AC adapters
- PLCs
- Switch mode power supplies
- DC/DC converters
- Microprocessor I/O interfaces
- · General impedance matching circuits

AGENCY APPROVALS

- UL1577 file no. E52744 system code Y
- <u>cUL</u> file no. E52744
- DIN EN 60747-5-5 (VDE 0884) available with option 1
- CSA 93751
- FIMKO

ORDERING INFORMATION				
I L 1	2 0 6	Α Τ	SOIC-8	
PART NUM	BER	TAPE AND REEL	6.1 mm	
AGENCY CERTIFIED / PACKAGE		CTR (%)		
AGENCY CENTIFIED / PACKAGE	1 mA			
UL, cUL, CSA, FIMKO	63 to 125	100 to 200	160 to 320	
SOIC-8	IL1206AT	IL1207AT	IL1208AT	

Note

Additional options may be possible, please contact sales office

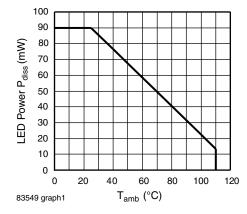


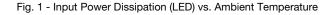
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ABSOLUTE MAXIMUM RATINGS PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
	TEST CONDITION	OTHIDOL	VALUE	OMIT
INPUT				T
Continuous forward current		I _F	60	mA
Peak reverse voltage		V_{R}	6.0	V
Power dissipation		P _{diss}	90	mW
Derate linearly from 25 °C			0.9	mW/°C
OUTPUT				
Collector emitter voltage		V _{CE}	70	V
Collector current		I _C	50	mA
Collector current	t < 1.0 ms	I _C	100	mA
Power dissipation		P _{diss}	150	mW
Derate linearly from 25 °C			1.5	mW/°C
COUPLER				
Isolation test voltage		V_{ISO}	4000	V_{RMS}
Operating temperature		T _{amb}	-55 to +110	°C
Total package dissipation (LED and detector)		P _{tot}	240	mW
Storage temperature		T _{stg}	-55 to +150	°C
Soldering temperature (1)	Max. 10 s, dip soldering distance to seating plane ³ 1.5 mm	T _{sld}	260	°C
Derate linearly from 25 °C			2.4	mW/°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SOP / SOIC)





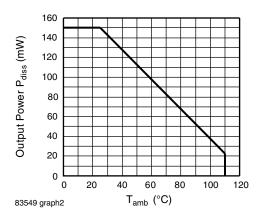


Fig. 2 - Output Power Dissipation vs. Ambient Temperature



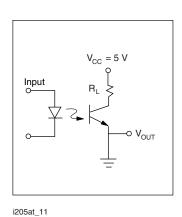
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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	I _F = 10 mA		V_{F}	-	1.3	1.5	V
Reverse current	V _R = 6 V		I _R	-	0.1	100	μΑ
Capacitance	V _R = 0 V		CI	-	13	-	pF
OUTPUT							
Collector emitter leakage current	V _{CE} = 10 V		I _{CEO}	-	5.0	50	nA
Collector emitter breakdown voltage	I _C = 100 μA		BV _{CEO}	70	-	-	V
Emitter collector breakdown voltage	I _E = 100 μA		BV _{ECO}	7.0	10	-	V
Collector base breakdown current			BV _{CBO}	70	-	-	V
Saturation voltage, collector emitter	$I_C = 2 \text{ mA}, I_F = 10 \text{ mA}$		V _{CEsat}	-	-	0.4	V
COUPLER							
DC current transfer ratio	I _F = 10 mA, V _{CE} = 5.0 V	IL1206AT	CTR	63	-	125	%
		IL1207AT	CTR	100	-	200	%
		IL1208AT	CTR	100	-	320	%
		IL1206AT	CTR	22	40	-	%
	$I_F = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V}$	IL1207AT	CTR	34	60	-	%
		IL1208AT	CTR	56	95	-	%
Capacitance (input to output)			C _{IO}	-	0.5	-	рF

Note

Minimum and maximum values were tested requirements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn-on time	$I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega, V_{CC} = 10 \text{ V}$	t _{on}	-	3.0	-	μs
Turn-off time	$I_{C} = 2 \text{ mA}, R_{L} = 100 \Omega, V_{CC} = 10 \text{ V}$	t _{off}	-	3.0	-	μs



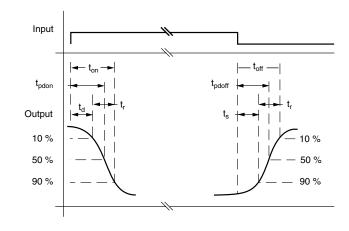


Fig. 1 - Switching Test Circuit

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SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification	According to IEC 68 part 1		-	55 / 110 / 21	-		
Pollution degree (DIN VDE 0109)			=	2.0	-		
Comparative tracking index		CTI	175	-	399		
V _{IOTM}	DIN IEC 112 / VDE 0303 part 1, group IIIa per DIN VDE 6110 175 399	V _{IOTM}	6000	-	=	V	
V _{IORM}		V_{IORM}	560	-	-	V	
Resistance (input to output)		R _{IO}	=	10 ¹²	-	Ω	
P _{SI}			-	-	350	mW	
I _{SI}			-	-	150	mA	
T _{SI}			-	-	165	°C	
Creepage distance			4.0	-	-	mm	
Clearance distance			4.0	-	-	mm	

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

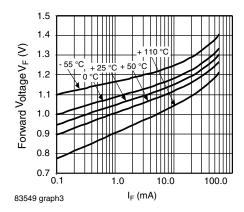


Fig. 2 - Diode Forward Voltage V_{F} vs. Forward Current

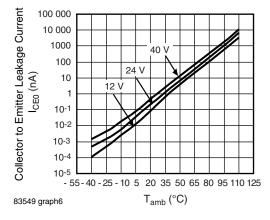


Fig. 4 - Collector to Emitter Current vs. Ambient Temperature

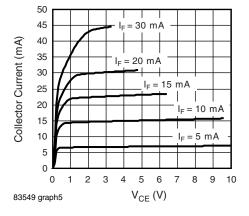


Fig. 3 - I_C (non-saturated) vs. V_{CE}

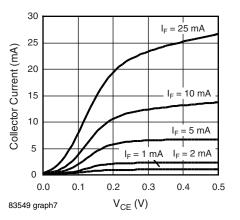


Fig. 5 - I_C (saturated) vs. V_{CE}

[•] As per IEC 60747-5-2, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits

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 I_{F}

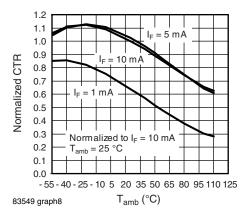


Fig. 6 - CTR Normalized to I_F = 10 mA vs. Ambient Temperature, (Saturated, V_{CE} = 0.4 V)

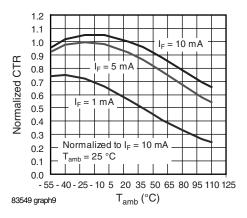


Fig. 7 - CTR Normalized to I_F = 10 mA vs. Ambient Temperature, (Non-Saturated, V_{CE} = 5 V)

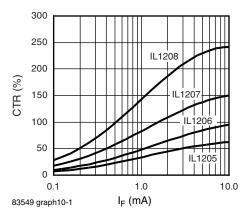


Fig. 8 - CTR vs. I_F , ($V_{CE} = 5 \text{ V}$, $T_{amb} = 25 \,^{\circ}\text{C}$) (Not Normalized)

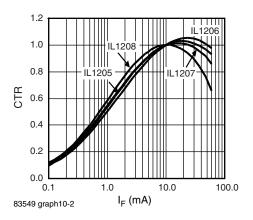


Fig. 9 - CTR vs. I_F, (V_{CE} = 5 V, T_{amb} = 25 °C) Normalized to = 10 mA, T_{amb} = 25 °C

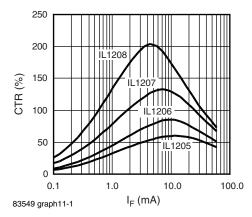


Fig. 10 - CTR vs. I_F Saturated, ($V_{CE} = 0.4 \text{ V}$, $T_{amb} = 25 \,^{\circ}\text{C}$)

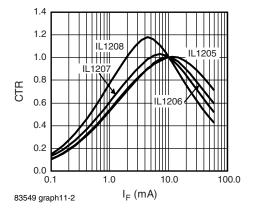


Fig. 11 - CTR vs. I_F Saturated, Normalized to I_F = 10 mA, $T_{amb} = 25\ ^{\circ}\text{C}$

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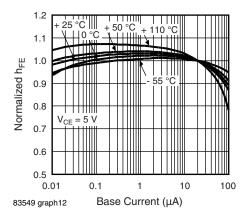


Fig. 12 - Normalized h_{FE} vs. Base Current and T_{amb} (Non-Saturated Condition)

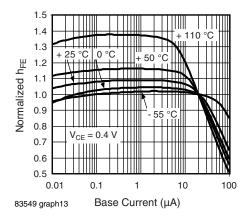


Fig. 13 - Normalized h_{FE} vs. Base Current and T_{amb} (Saturated Condition)

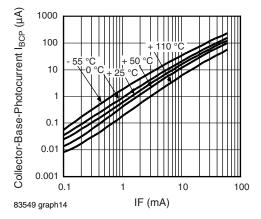


Fig. 14 - Collector Base Photocurrent vs. I_F

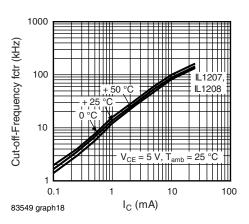


Fig. 15 - Cut-Off-Frequency (- 3 dB) vs. Collector Current

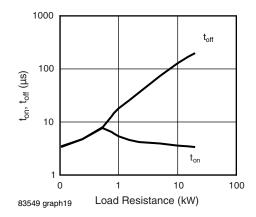


Fig. 16 - Switching Time $t_{\text{on}},\,t_{\text{off}}\,\text{vs.}$ Load Resistance

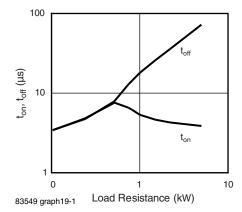


Fig. 17 - Switching Time t_{on} , t_{off} vs. Load Resistance (100 Ω to 5000 Ω)



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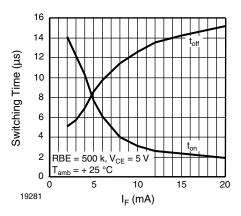


Fig. 18 - Switching Time vs. I_F

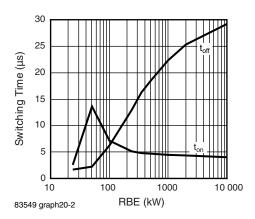
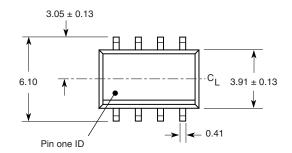
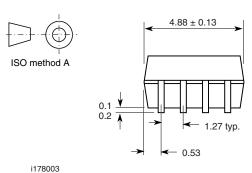
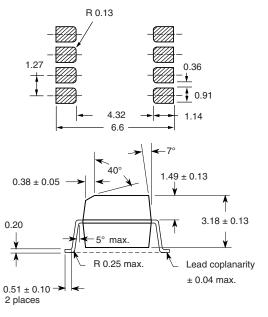


Fig. 19 - Switching Time vs. RBE, $I_F = 10 \text{ mA}$

PACKAGE DIMENSIONS in millimeters







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